









SN74AXC8T245 SCES875C - MARCH 2018 - REVISED JANUARY 2024

# SN74AXC8T245 8-Bit Dual-Supply Bus Transceiver With Configurable Voltage **Translation and Tri-State Outputs**

#### 1 Features

- Qualified fully configurable dual-rail design allows each port to operate with a power supply range from 0.65V to 3.6V
- Operating temperature from -40°C to +125°C
- Multiple direction-control pins to allow simultaneous up and down translation
- Up to 380Mbps support when translating from 1.8V to 3.3V
- V<sub>CC</sub> isolation feature to effectively Isolate both buses in a power-down scenario
- Partial power-down mode to limit backflow current in a power-down scenario
- Compatible with SN74AVC8T245 and 74AVC8T245 level shifters
- Latch-up performance exceeds 100mA per JESD 78. class II
- ESD protection exceeds JESD 22
  - 8000-V human-body model
  - 1000-V charged-device model

#### 2 Applications

- Enterprise and communications
- Industrial
- Personal electronics
- Wireless infrastructure
- **Building automation**
- Point of sale

#### 3 Description

The SN74AXC8T245 device is an 8-bit non-inverting bus transceiver that resolves voltage level mismatch between devices operating at the latest voltage nodes (0.7V, 0.8V, and 0.9V) and devices operating at industry standard voltage nodes (1.8V, 2.5V, and 3.3V) and vice versa.

The device operates by using two independent powersupply rails ( $V_{CCA}$  and  $V_{CCB}$ ) that operate as low as 0.65V. Data pins A1 through A8 are designed to track V<sub>CCA</sub>, which accepts any supply voltage from 0.65V to 3.6V. Data pins B1 through B8 are designed to track V<sub>CCB</sub>, which accepts any supply voltage from 0.65V to 3.6V.

SN74AXC8T245 device is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level of the direction-control inputs (DIR1 and DIR2). The output-enable (OE) input is used to disable the outputs so the buses are effectively isolated.

The SN74AXC8T245 device is designed so the control pins (DIR and  $\overline{OE}$ ) are referenced to  $V_{CCA}$ .

This device is fully specified for partial-power-down applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry disables the outputs when the device is powered down. This inhibits current backflow into the device which prevents damage to the device.

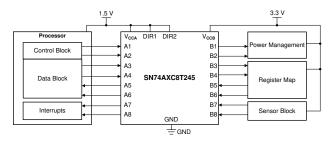
The V<sub>CC</sub> isolation feature is designed so that if either V<sub>CC</sub> input supply is below 100mV, all level shifter outputs are disabled and placed into a highimpedance state.

To put the level shifter I/Os in the high-impedance state during power up or power down, tie  $\overline{OE}$  to  $V_{CCA}$ through a pullup resistor; the current-sinking capability of the driver determines the minimum value of the resistor.

#### **Package Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>
	PW (TSSOP, 24)	7.8mm × 6.4mm
SN74AXC8T245	RHL (VQFN, 24)	5.5mm × 3.5mm
	RJW (UQFN, 24)	4mm × 2mm

- (1) For more information, see Section 11
- (2)The package size (length × width) is a nominal value and includes pins, where applicable.



Typical Application Schematic



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## **4 Pin Configuration and Functions**

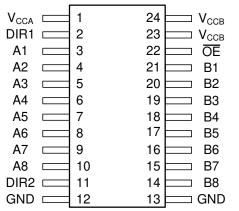
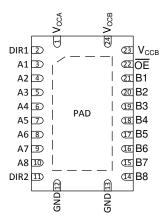


Figure 4-1. PW Package, 24-Pin TSSOP (Top View)



PAD — may be grounded (recommended) or left floating.

Figure 4-2. RHL 24-Pin VQFN (Top View)

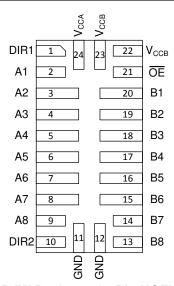


Figure 4-3. RJW Package, 24-Pin UQFN (Top View)

**Table 4-1. Pin Functions** 

	PIN		<b>-</b> VO=(1)	DECODINE
NAME	PW, RHL	RJW	TYPE <sup>(1)</sup>	DESCRIPTION
A1	3	2	I/O	Input/output A1. Referenced to V <sub>CCA</sub> .
A2	4	3	I/O	Input/output A2. Referenced to V <sub>CCA</sub> .
A3	5	4	I/O	Input/output A3. Referenced to V <sub>CCA</sub> .
A4	6	5	I/O	Input/output A4. Referenced to V <sub>CCA</sub> .
A5	7	6	I/O	Input/output A5. Referenced to V <sub>CCA</sub> .
A6	8	7	I/O	Input/output A6. Referenced to V <sub>CCA</sub> .
A7	9	8	I/O	Input/output A7. Referenced to V <sub>CCA</sub> .
A8	10	9	I/O	Input/output A8. Referenced to V <sub>CCA</sub> .
B1	21	20	I/O	Input/output B1. Referenced to V <sub>CCB</sub> .
B2	20	19	I/O	Input/output B2. Referenced to V <sub>CCB</sub> .
В3	19	18	I/O	Input/output B3. Referenced to V <sub>CCB</sub> .
B4	18	17	I/O	Input/output B4. Referenced to V <sub>CCB</sub> .
B5	17	16	I/O	Input/output B5. Referenced to V <sub>CCB</sub> .
B6	16	15	I/O	Input/output B6. Referenced to V <sub>CCB</sub> .
B7	15	14	I/O	Input/output B7. Referenced to V <sub>CCB</sub> .
В8	14	13	I/O	Input/output B8. Referenced to V <sub>CCB</sub> .
DIR1	2	1	I	Direction-control signal 1. Referenced to V <sub>CCA</sub> .
DIR2	11	10	I	Direction-control signal 2. Referenced to V <sub>CCA</sub> . Tie to GND to maintain backward compatibility with SN74AVC8T245 device.
GND	12	11	_	Ground
GND	13	12	_	Ground
ŌĒ	22	21	I	Output Enable. Pull to GND to enable all outputs. Pull to $V_{CCA}$ to place all outputs in high-impedance mode. Referenced to $V_{CCA}$ .
V <sub>CCA</sub>	1	24	_	A-port supply voltage. 0.65V ≤ V <sub>CCA</sub> ≤ 3.6V
V	23	22	_	B-port supply voltage. 0.65V ≤ V <sub>CCB</sub> ≤ 3.6V
V <sub>CCB</sub>	24	23	_	B-port supply voltage. 0.65V ≤ V <sub>CCB</sub> ≤ 3.6V

(1) PAD - may be grounded (recommended) or left floating.



### **5 Specifications**

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Supply voltage, V <sub>CCA</sub>		-0.5	4.2	V
Supply voltage, V <sub>CCB</sub>		-0.5	4.2	V
	I/O ports (A port)	-0.5	4.2	
Input voltage, V <sub>I</sub> <sup>(2)</sup>	I/O ports (B port)	-0.5	4.2	V
	Control inputs	-0.5	4.2	
Voltage applied to any output	A port	-0.5	4.2	V
in the high-impedance or power-off state, V <sub>O</sub> <sup>(2)</sup>	B port	-0.5	4.2	V
Voltage applied to any output in the high or low state, $V_{O}$ (2) (3)	A port	-0.5	V <sub>CCA</sub> + 0.2	V
voltage applied to any output in the high of low state, $v_0 \leftarrow v_0$	B port	-0.5	V <sub>CCB</sub> + 0.2	V
Input clamp current, I <sub>IK</sub>	V <sub>I</sub> < 0	-50		mA
Output clamp current, I <sub>OK</sub>	V <sub>O</sub> < 0	-50		mA
Continuous output current, I <sub>O</sub>		-50	50	mA
Continuous current through V <sub>CCA</sub> , V <sub>CCB</sub> , or GND		-100	100	mA
Junction Temperature, T <sub>J</sub>			150	°C
Storage temperature, T <sub>stg</sub>		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The output positive-voltage rating may be exceeded up to 4.2V maximum if the output current rating is observed.

#### 5.2 ESD Ratings

				VALUE	UNIT
,	\/	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±8000	V
	V <sub>(ESD)</sub>	Liectiostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## **5.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted) (1) (2) (3)

				MIN	MAX	UNIT
V <sub>CCA</sub>	Supply voltage			0.65	3.6	V
V <sub>CCB</sub>	Supply voltage			0.65	3.6	V
			V <sub>CCI</sub> = 0.65V - 0.75V	V <sub>CCI</sub> × 0.70		
			V <sub>CCI</sub> = 0.76V - 1V	V <sub>CCI</sub> × 0.70		
		Data inputs	V <sub>CCI</sub> = 1.1V - 1.95V	V <sub>CCI</sub> × 0.65		
			V <sub>CCI</sub> = 2.3V - 2.7V	1.6		
V	High-level input voltage		V <sub>CCI</sub> = 3V - 3.6V	2		V
$V_{IH}$	nigri-level iriput voltage		V <sub>CCA</sub> = 0.65V - 0.75V	V <sub>CCA</sub> × 0.70		V
		Control inputs	V <sub>CCA</sub> = 0.76V - 1V	V <sub>CCA</sub> × 0.70		
		(DIR, OE)	V <sub>CCA</sub> = 1.1V - 1.95V	V <sub>CCA</sub> × 0.65		
		Referenced to V <sub>CCA</sub>	V <sub>CCA</sub> = 2.3V - 2.7V	1.6		
			V <sub>CCA</sub> = 3V - 3.6V	2		
			V <sub>CCI</sub> = 0.65V - 0.75V		V <sub>CCI</sub> × 0.30	
			V <sub>CCI</sub> = 0.76V - 1V		V <sub>CCI</sub> × 0.30	
		Data inputs	V <sub>CCI</sub> = 1.1V - 1.95V		V <sub>CCI</sub> × 0.35	
			V <sub>CCI</sub> = 2.3V - 2.7V		0.7	
V <sub>IL</sub>	Low-level input voltage		V <sub>CCI</sub> = 3V - 3.6V		0.8	V
V IL	Low-level input voltage		V <sub>CCA</sub> = 0.65V - 0.75V		V <sub>CCA</sub> × 0.30	V
		Control inputs	V <sub>CCA</sub> = 0.76V - 1V		V <sub>CCA</sub> × 0.30	
		(DIR, OE)	V <sub>CCA</sub> = 1.1V - 1.95V		V <sub>CCA</sub> × 0.35	
		Referenced to V <sub>CCA</sub>	$V_{CCA} = 2.3V - 2.7V$		0.7	
			V <sub>CCA</sub> = 3V - 3.6V		0.8	
VI	Input voltage <sup>(3)</sup>			0	3.6	V
V-	Output voltage	Active state		0	V <sub>CCO</sub> (2)	V
Vo	Output voltage  Active state  Tri-state	Tri-state		0	3.6	V
Δt/Δν	Input transition rise or fall rate	)			10	ns/V
T <sub>A</sub>	Operating free-air temperatur	e		-40	125	°C

- $V_{CCI}$  is the  $V_{CC}$  associated with the input port.  $V_{CCO}$  is the  $V_{CC}$  associated with the output port. All unused data inputs of the device must be held at  $V_{CCI}$  or GND for proper device operation. See the *Implications of Slow or Floating* CMOS Inputs application report.

### **5.4 Thermal Information**

			SN74AXC8T245	5	
	THERMAL METRIC	PW (TSSOP)	RHL (VQFN)	RJW (UQFN)	UNIT
		24 PINS	24 PINS	24 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	92.0	35.0	123.1	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	29.3	39.9	65.0	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	46.7	13.8	55.3	°C/W
Ψлт	Junction-to-top characterization parameter	1.5	0.3	3.9	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	46.2	13.8	54.9	°C/W
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	1.4	N/A	°C/W

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#### 5.5 Electrical Characteristics

Over recommended operating free-air temperature range (unless otherwise noted)(1)

D/	ARAMETER	TES	CONDITIONS	V <sub>CCA</sub>	V <sub>CCB</sub>	-40°C	to 85°C		–40°C t	o 125°C		UNI
Ρ,	ARAMETER	IES	CONDITIONS	VCCA	V CCB	MIN	TYP <sup>(2)</sup>	MAX	MIN	TYP <sup>(2)</sup>	MAX	UNI
			$I_{OH} = -100 \mu A$	0.7V - 3.6V	0.7V - 3.6V	V <sub>CCO</sub> – 0.1			$V_{CCO} - 0.1$			
			$I_{OH} = -50\mu A$	0.65V	0.65V	0.55			0.55			
			I <sub>OH</sub> = -200μA	0.76V	0.76V	0.58			0.58			
	High-level		I <sub>OH</sub> = -500μA	0.85V	0.85V	0.65			0.65			
$V_{OH}$	output	V <sub>I</sub> = V <sub>IH</sub>	I <sub>OH</sub> = -3mA	1.1V	1.1V	0.85			0.85			V
	voltage		I <sub>OH</sub> = -6mA	1.4V	1.4V	1.05			1.05			
			I <sub>OH</sub> = -8mA	1.65V	1.65V	1.2			1.2			
			I <sub>OH</sub> = -9mA	2.3V	2.3V	1.75			1.75			
			I <sub>OH</sub> = -12mA	3V	3V	2.3			2.3			
			I <sub>OL</sub> = 100μA	0.7V - 3.6V	0.7V - 3.6V			0.1			0.1	
			I <sub>OL</sub> = 50μA	0.65V	0.65V			0.1			0.1	
			I <sub>OL</sub> = 200μA	0.76V	0.76V			0.18			0.18	
	Low-level		I <sub>OL</sub> = 500μA	0.85V	0.85V			0.2			0.2	
V <sub>OL</sub>	output	V <sub>I</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 3mA	1.1V	1.1V			0.25			0.25	V
	voltage		I <sub>OL</sub> = 6mA	1.4V	1.4V			0.35			0.35	
			I <sub>OL</sub> = 8mA	1.65V	1.65V			0.45			0.45	
			I <sub>OL</sub> = 9mA	2.3V	2.3V			0.55			0.55	
			I <sub>OL</sub> = 12mA	3V	3V			0.7			0.7	
l <sub>l</sub>	Input leakage current	Control In	puts (DIR, OE): or GND	0.65V - 3.6V	0.65V - 3.6V	-0.5		0.5	-1		1	μΑ
	Partial power	A Port: V <sub>I</sub> or V <sub>O</sub> =	: 0V - 3.6V	0V	0V - 3.6V	-4		4	-8		8	
l <sub>off</sub>	down current	B Port: V <sub>I</sub> or V <sub>O</sub> =	: 0V - 3.6V	0V - 3.6V	0V	-4		4	-8		8	μA
	High- impedance	A Port: V <sub>O</sub> = V <sub>CCO</sub> or GND, O	or GND, V <sub>I</sub> = V <sub>CCI</sub> DE = V <sub>IH</sub>	3.6V	3.6V	-4		4	-8		8	
loz	state output current	B Port: V <sub>O</sub> = V <sub>CC0</sub> or GND, 0	or GND, V <sub>I</sub> = V <sub>CCI</sub> DE = V <sub>IH</sub>	3.6V	3.6V	-4		4	-8		8	μA
				0.65V - 3.6V	0.65V - 3.6V			19			40	
CCA	V <sub>CCA</sub> supply current	V <sub>I</sub> = V <sub>CCI</sub>	or GND, I <sub>O</sub> = 0mA	0V	3.6V	-2			-12			μΑ
	ourront			3.6V	0V			12			25	
				0.65V - 3.6V	0.65V - 3.6V			18			38	
ССВ	V <sub>CCB</sub> supply current	V <sub>I</sub> = V <sub>CCI</sub>	or GND, I <sub>O</sub> = 0mA	0V	3.6V			12			25	μΑ
	ourront			3.6V	0V	-2			-12			
I <sub>CCA</sub> + I <sub>CCB</sub>	Combined supply current	V <sub>I</sub> = V <sub>CCI</sub>	or GND, I <sub>O</sub> = 0mA	0.65V - 3.6V	0.65V - 3.6V			25			55	μΑ
C <sub>i</sub>	Input capacitance	Control In	puts (DIR, <del>OE</del> ): or GND	3.3V	3.3V		4.5			4.5		pF
C <sub>io</sub>	Data I/O capacitance	Ports A ar OE = V <sub>CC</sub> 1MHz -16	nd B: <sub>A</sub> , V <sub>O</sub> = 1.65V DC + dBm sine wave	3.3V	3.3V		5.7			5.7		pF

 $V_{CCO}$  is the  $V_{CC}$  associated with the output port. All typical values are for  $T_A$  = 25°C

## 5.6 Switching Characteristics, $V_{CCA} = 0.7V$

See Figure 6-1 and Figure 6-2 for test circuit and loading conditions. See Figure 6-3 and Figure 6-4 for measurement waveforms.

						B-POR	T SUPPLY '	VOLTAGE (	(V <sub>CCB</sub> )			
P.	ARAMETER	TEST CONDITIONS		0.7V ± 0.05V		0.8V ± 0.04V		0.9V ± 0.045V		1.2V ± 0.1V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	172	0.5	114	0.5	82	0.5	49	
	Propagation	to output B	-40°C to 125°C	0.5	172	0.5	114	0.5	82	0.5	49	] no
t <sub>pd</sub>	delay	From input B	–40°C to 85°C	0.5	172	0.5	153	0.5	126	0.5	88	ns
		to output A	-40°C to 125°C	0.5	172	0.5	153	0.5	126	0.5	88	]
		From input OE to output A	–40°C to 85°C	0.5	192	0.5	192	0.5	192	0.5	192	
	Disable time		-40°C to 125°C	0.5	195	0.5	195	0.5	195	0.5	195	] no
t <sub>dis</sub>	Disable time	From input OE	–40°C to 85°C	0.5	156	0.5	129	0.5	118	0.5	120	ns
		to output B	-40°C to 125°C	0.5	157	0.5	129	0.5	120	0.5	122	
		From input OE	–40°C to 85°C	0.5	237	0.5	237	0.5	237	0.5	237	
	Enable time	to output A	-40°C to 125°C	0.5	237	0.5	237	0.5	237	0.5	237	1
t <sub>en</sub>	Enable time	From input OE	–40°C to 85°C	0.5	223	0.5	145	0.5	106	0.5	74	ns
		to output B	-40°C to 125°C	0.5	223	0.5	145	0.5	106	0.5	74	1

## Switching Characteristics, $V_{CCA} = 0.7V$

						B-POR	T SUPPLY \	OLTAGE (	V <sub>CCB</sub> )			
P.	ARAMETER	TEST CONDITIONS		ONS 1.5V ± 0.		1.8V ± 0.15V		2.5V ± 0.2V		3.3V ± 0.3V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	46	0.5	49	0.5	61	0.5	142	
	Propagation	to output B	-40°C to 125°C	0.5	46	0.5	49	0.5	61	0.5	142	
t <sub>pd</sub>	delay	From input B	–40°C to 85°C	0.5	83	0.5	82	0.5	81	0.5	81	ns
		to output A	-40°C to 125°C	0.5	83	0.5	82	0.5	81	0.5	81	
		From input OE to output A	–40°C to 85°C	0.5	192	0.5	192	0.5	192	0.5	192	
	Disable time		-40°C to 125°C	0.5	195	0.5	195	0.5	195	0.5	195	
t <sub>dis</sub>	Disable time	From input OE	–40°C to 85°C	0.5	69	0.5	66	0.5	67	0.5	150	ns
		to output B	-40°C to 125°C	0.5	70	0.5	67	0.5	67	0.5	150	
		From input OE	–40°C to 85°C	0.5	237	0.5	237	0.5	237	0.5	237	
	F	to output A	-40°C to 125°C	0.5	237	0.5	237	0.5	237	0.5	237	
t <sub>en</sub>	Enable time	From input OE	-40°C to 85°C	0.5	68	0.5	69	0.5	84	0.5	552	ns
		to output B	-40°C to 125°C	0.5	68	0.5	69	0.5	84	0.5	552	1



## 5.7 Switching Characteristics, $V_{CCA} = 0.8V$

See Figure 6-1 and Figure 6-2 for test circuit and loading conditions. See Figure 6-3 and Figure 6-4 for measurement waveforms.

						B-POR	T SUPPLY	VOLTAGE	(V <sub>CCB</sub> )			
P	ARAMETER	TEST CONDITIONS		0.7V ± 0.05V		0.8V ± 0.04V		0.9V ± 0.045V		1.2V ± 0.1V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	1
		From input A	-40°C to 85°C	0.5	153	0.5	95	0.5	62	0.5	32	
	Propagation	to output B	-40°C to 125°C	0.5	153	0.5	95	0.5	62	0.5	32	ns
t <sub>pd</sub>	delay	From input B	-40°C to 85°C	0.5	114	0.5	95	0.5	78	0.5	52	1115
		to output A	-40°C to 125°C	0.5	114	0.5	95	0.5	78	0.5	52	1
		From input OE	-40°C to 85°C	0.5	101	0.5	101	0.5	101	0.5	101	
	Disable time	to output A	-40°C to 125°C	0.5	103	0.5	103	0.5	103	0.5	103	]
t <sub>dis</sub>	Disable time	From input OE	-40°C to 85°C	0.5	141	0.5	114	0.5	104	0.5	106	ns
		to output B	-40°C to 125°C	0.5	142	0.5	115	0.5	106	0.5	109	1
		From input OE	-40°C to 85°C	0.5	102	0.5	102	0.5	102	0.5	102	
	Enable time	to output A	-40°C to 125°C	0.5	102	0.5	102	0.5	102	0.5	102	1
t <sub>en</sub>	Enable time	From input OE	-40°C to 85°C	0.5	202	0.5	124	0.5	86	0.5	52	ns
		to output B	-40°C to 125°C	0.5	202	0.5	124	0.5	86	0.5	52	1

## Switching Characteristics, V<sub>CCA</sub> = 0.8V

						B-POR	T SUPPLY	VOLTAGE (	V <sub>CCB</sub> )			
P	ARAMETER	TEST C	ONDITIONS	1.5V	± 0.1V	1.8V ±	1.8V ± 0.15V		0.2V	3.3V ± 0.3V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	26	0.5	25	0.5	25	0.5	35	
	Propagation	to output B	-40°C to 125°C	0.5	26	0.5	25	0.5	25	0.5	35	ns
t <sub>pd</sub>	delay	From input B	-40°C to 85°C	0.5	42	0.5	41	0.5	40	0.5	40	1115
		to output A	-40°C to 125°C	0.5	42	0.5	41	0.5	40	0.5	40	
		From input OE	-40°C to 85°C	0.5	101	0.5	101	0.5	101	0.5	101	
	Disable time	to output A	-40°C to 125°C	0.5	103	0.5	103	0.5	103	0.5	103	
t <sub>dis</sub>	Disable time	From input OE	-40°C to 85°C	0.5	55	0.5	51	0.5	49	0.5	51	ns
		to output B	-40°C to 125°C	0.5	57	0.5	53	0.5	50	0.5	52	
		From input OE	-40°C to 85°C	0.5	102	0.5	102	0.5	102	0.5	102	
	Enable time	to output A	-40°C to 125°C	0.5	102	0.5	102	0.5	102	0.5	102	]
t <sub>en</sub>		From input OE	-40°C to 85°C	0.5	44	0.5	43	0.5	45	0.5	58	ns
	From input OE to output B	to output B	-40°C to 125°C	0.5	44	0.5	43	0.5	45	0.5	58	

## 5.8 Switching Characteristics, $V_{CCA} = 0.9V$

See Figure 6-1 and Figure 6-2 for test circuit and loading conditions. See Figure 6-3 and Figure 6-4 for measurement waveforms.

						B-POR	SUPPLY \	/OLTAGE	(V <sub>CCB</sub> )			
P/	ARAMETER	TEST CO	ONDITIONS	0.7V ±	t 0.05V	0.8V ±	0.04V	0.9V ±	t 0.045V	1.2V	± 0.1V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	127	0.5	78	0.5	52	0.5	23	
	Propagation	to output B	-40°C to 125°C	0.5	127	0.5	78	0.5	52	0.5	23	
t <sub>pd</sub>	delay	From input B	-40°C to 85°C	0.5	82	0.5	63	0.5	52	0.5	39	ns
		to output A	-40°C to 125°C	0.5	82	0.5	63	0.5	52	0.5	39	
		From input OE	–40°C to 85°C	0.5	125	0.5	125	0.5	125	0.5	125	
	Disable time	to output A	-40°C to 125°C	0.5	128	0.5	128	0.5	128	0.5	128	, no
t <sub>dis</sub>	Disable time	From input OE	-40°C to 85°C	0.5	131	0.5	105	0.5	96	0.5	99	ns
		to output B	-40°C to 125°C	0.5	133	0.5	107	0.5	98	0.5	101	
		From input OE	-40°C to 85°C	0.5	124	0.5	124	0.5	124	0.5	124	
t <sub>en</sub>	Enable time	to output A	-40°C to 125°C	0.5	128	0.5	128	0.5	128	0.5	128	1
	Enable time	From input OE	-40°C to 85°C	0.5	191	0.5	113	0.5	75	0.5	41	ns
		to output B	-40°C to 125°C	0.5	191	0.5	113	0.5	75	0.5	41	1

## Switching Characteristics, V<sub>CCA</sub> = 0.9V

						B-POF	RT SUPPLY	VOLTAGE	(V <sub>CCB</sub> )			
P	ARAMETER	TEST C	ONDITIONS	1.5V	± 0.1V	1.8V	± 0.15V	2.5V	± 0.2V	3.3V	± 0.3V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	17	0.5	15	0.5	14	0.5	17	
	Propagation	to output B	-40°C to 125°C	0.5	17	0.5	15	0.5	14	0.5	17	]
t <sub>pd</sub>	delay	From input B	–40°C to 85°C	0.5	28	0.5	24	0.5	22	0.5	22	ns
		to output A	-40°C to 125°C	0.5	28	0.5	24	0.5	22	0.5	22	
		From input OE	–40°C to 85°C	0.5	125	0.5	125	0.5	125	0.5	125	
	Disable time	to output A	-40°C to 125°C	0.5	128	0.5	128	0.5	128	0.5	128	
t <sub>dis</sub>	Disable time	From input OE	–40°C to 85°C	0.5	47	0.5	44	0.5	40	0.5	73	ns
		to output B	-40°C to 125°C	0.5	50	0.5	46	0.5	42	0.5	73	
		From input OE	–40°C to 85°C	0.5	124	0.5	124	0.5	124	0.5	124	
	Enable time	to output A	-40°C to 125°C	0.5	128	0.5	128	0.5	128	0.5	128	
t <sub>en</sub>	Enable time	From input OE	-40°C to 85°C	0.5	34	0.5	32	0.5	31	0.5	35	ns
		to output B	-40°C to 125°C	0.5	34	0.5	32	0.5	31	0.5	35	1



## 5.9 Switching Characteristics, $V_{CCA} = 1.2V$

See Figure 6-1 and Figure 6-2 for test circuit and loading conditions. See Figure 6-3 and Figure 6-4 for measurement waveforms.

						B-PORT	SUPPLY V	OLTAGE	(V <sub>CCB</sub> )			
PA	RAMETER	TEST C	ONDITIONS	0.7V :	± 0.05V	0.8V	± 0.04V	0.9V ±	0.045V	1.2V	± 0.1V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	88	0.5	52	0.5	39	0.5	15	
	Propagation	to output B	-40°C to 125°C	0.5	88	0.5	52	0.5	39	0.5	15	ns
t <sub>pd</sub>	delay	From input B	–40°C to 85°C	0.5	49	0.5	32	0.5	23	0.5	15	115
		to output A	-40°C to 125°C	0.5	49	0.5	32	0.5	23	0.5	15	
		From input	–40°C to 85°C	0.5	87	0.5	87	0.5	87	0.5	87	
	Disable time	OE to output A	-40°C to 125°C	0.5	91	0.5	91	0.5	91	0.5	91	ns
t <sub>dis</sub>	Disable tillle	From input	–40°C to 85°C	0.5	119	0.5	94	0.5	85	0.5	89	115
		OE to output B	–40°C to 125°C	0.5	121	0.5	96	0.5	88	0.5	93	
	F	From input	–40°C to 85°C	0.5	34	0.5	34	0.5	34	0.5	34	
	Enable time	OE to output A	-40°C to 125°C	0.5	36	0.5	36	0.5	36	0.5	36	ns
t <sub>en</sub>	LITADIE UITIE	From input	–40°C to 85°C	0.5	168	0.5	98	0.5	61	0.5	29	115
		OE to output B	-40°C to 125°C	0.5	168	0.5	98	0.5	61	0.5	30	

# Switching Characteristics, $V_{CCA} = 1.2V$

						B-POI	RT SUPPLY	VOLTAGE	(V <sub>CCB</sub> )			
P.	ARAMETER	TEST C	ONDITIONS	1.5V	± 0.1V	1.8V	± 0.15V	2.5V	± 0.2V	3.3V	± 0.3V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	10	0.5	9	0.5	7	0.5	7	
	Propagation	to output B	-40°C to 125°C	0.5	10	0.5	9	0.5	7	0.5	8	ns
t <sub>pd</sub>	F	From input B	-40°C to 85°C	0.5	13	0.5	11	0.5	8	0.5	7	1115
		to output A	-40°C to 125°C	0.5	13	0.5	11	0.5	8	0.5	7	
		From input OE	-40°C to 85°C	0.5	87	0.5	87	0.5	87	0.5	87	
		to output A	-40°C to 125°C	0.5	91	0.5	91	0.5	91	0.5	91	ns
t <sub>dis</sub>	Disable time	From input OE	-40°C to 85°C	0.5	38	0.5	35	0.5	31	0.5	29	1115
	t	to output B	-40°C to 125°C	0.5	41	0.5	38	0.5	33	0.5	31	
		From input OE	-40°C to 85°C	0.5	34	0.5	34	0.5	34	0.5	34	
	Enable time	to output A	-40°C to 125°C	0.5	36	0.5	36	0.5	36	0.5	36	]
t <sub>en</sub>	Eliable tille	From input OE	-40°C to 85°C	0.5	22	0.5	19	0.5	17	0.5	17	ns
		to output B	-40°C to 125°C	0.5	23	0.5	20	0.5	18	0.5	18	]

## 5.10 Switching Characteristics, $V_{CCA} = 1.5V$

See Figure 6-1 and Figure 6-2 for test circuit and loading conditions. See Figure 6-3 and Figure 6-4 for measurement waveforms.

						B-POR	T SUPPLY \	/OLTAGE (	V <sub>CCB</sub> )			
F	PARAMETER	TEST CO	NDITIONS	0.7V :	± 0.05V	0.8V	t 0.04V	0.9V ±	0.045V	1.2V ±	t 0.1V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	84	0.5	42	0.5	28	0.5	13	
	Propagation	to output B	–40°C to 125°C	0.5	84	0.5	42	0.5	28	0.5	13	ns
t <sub>pd</sub>	delay	From input B	-40°C to 85°C	0.5	46	0.5	26	0.5	17	0.5	10	115
		to output A	–40°C to 125°C	0.5	46	0.5	26	0.5	17	0.5	10	
		From input OE	-40°C to 85°C	0.5	34	0.5	34	0.5	34	0.5	34	
	Disable time	to output A	–40°C to 125°C	0.5	37	0.5	37	0.5	37	0.5	37	no
t <sub>dis</sub>	Disable time	From input OE	-40°C to 85°C	0.5	115	0.5	89	0.5	80	0.5	85	ns
		to output B	-40°C to 125°C	0.5	117	0.5	91	0.5	83	0.5	89	
		From input OE	–40°C to 85°C	0.5	21	0.5	21	0.5	21	0.5	21	
	Enable time	to output A	-40°C to 125°C	0.5	23	0.5	23	0.5	23	0.5	23	
t <sub>en</sub>	Enable time	From input OE	–40°C to 85°C	0.5	159	0.5	90	0.5	55	0.5	24	ns
		to output B	-40°C to 125°C	0.5	159	0.5	90	0.5	55	0.5	25	

## Switching Characteristics, $V_{CCA} = 1.5V$

						B-POR	T SUPPLY	VOLTAGE	(V <sub>CCB</sub> )			
ı	PARAMETER	TEST CC	NDITIONS	1.5V	± 0.1V	1.8V :	± 0.15V	2.5V	± 0.2V	3.3V	± 0.3V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	9	0.5	7	0.5	6	0.5	5	
	Propagation	to output B	–40°C to 125°C	0.5	9	0.5	7	0.5	6	0.5	6	20
t <sub>pd</sub>	delay	From input B	-40°C to 85°C	0.5	9	0.5	7	0.5	6	0.5	5	ns
		to output A	-40°C to 125°C	0.5	9	0.5	8	0.5	6	0.5	5	
		From input OE	-40°C to 85°C	0.5	34	0.5	34	0.5	34	0.5	34	
	Disable time	to output A	-40°C to 125°C	0.5	37	0.5	37	0.5	37	0.5	37	no
t <sub>dis</sub>	Disable time	From input OE	–40°C to 85°C	0.5	35	0.5	31	0.5	28	0.5	25	ns
		to output B	–40°C to 125°C	0.5	38	0.5	34	0.5	31	0.5	27	
		From input OE	–40°C to 85°C	0.5	21	0.5	21	0.5	21	0.5	21	
t <sub>en</sub>	Enable time	to output A	–40°C to 125°C	0.5	23	0.5	23	0.5	23	0.5	23	
	Enable time	From input OE	-40°C to 85°C	0.5	17	0.5	15	0.5	12	0.5	11	ns
		to output B	-40°C to 125°C	0.5	18	0.5	15	0.5	13	0.5	12	



## 5.11 Switching Characteristics, V<sub>CCA</sub> = 1.8V

See Figure 6-1 and Figure 6-2 for test circuit and loading conditions. See Figure 6-3 and Figure 6-4 for measurement waveforms.

						B-POR	SUPPLY \	OLTAGE (	V <sub>CCB</sub> )			
P	PARAMETER	TEST CO	NDITIONS	0.7V	± 0.05V	0.8V	t 0.04V	0.9V ±	0.045V	1.2V	± 0.1V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	82	0.5	41	0.5	24	0.5	11	
	Propagation	to output B	-40°C to 125°C	0.5	82	0.5	41	0.5	24	0.5	11	no
t <sub>pd</sub>	delay	From input B	-40°C to 85°C	0.5	49	0.5	25	0.5	15	0.5	9	ns
		to output A	-40°C to 125°C	0.5	49	0.5	25	0.5	15	0.5	9	
		From input OE	-40°C to 85°C	0.5	37	0.5	37	0.5	37	0.5	37	
	Disable time	to output A	-40°C to 125°C	0.5	40	0.5	40	0.5	40	0.5	40	
t <sub>dis</sub>	Disable time	From input OE	-40°C to 85°C	0.5	113	0.5	87	0.5	78	0.5	83	ns
		to output B	-40°C to 125°C	0.5	115	0.5	89	0.5	81	0.5	87	
		From input OE	-40°C to 85°C	0.5	17	0.5	17	0.5	17	0.5	17	
t <sub>en</sub>	For abla tions	to output A	-40°C to 125°C	0.5	19	0.5	19	0.5	19	0.5	19	
	Enable time	From input OE	-40°C to 85°C	0.5	157	0.5	88	0.5	54	0.5	23	ns
		to output B	-40°C to 125°C	0.5	157	0.5	88	0.5	54	0.5	23	

## Switching Characteristics, $V_{CCA} = 1.8V$

						B-POR	SUPPLY V	OLTAGE (	(V <sub>CCB</sub> )			
F	PARAMETER	TEST CO	NDITIONS	1.5V :	± 0.1V	1.8V :	± 0.15V	2.5V	± 0.2V	3.3V :	± 0.3V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	8	0.5	6	0.5	5	0.5	5	
	Propagation	to output B	-40°C to 125°C	0.5	8	0.5	7	0.5	6	0.5	5	ns
t <sub>pd</sub>	delay	From input B	-40°C to 85°C	0.5	7	0.5	6	0.5	5	0.5	4	115
	to output A	to output A	-40°C to 125°C	0.5	7	0.5	7	0.5	5	0.5	4	
	From input OE to output A	From input OE	-40°C to 85°C	0.5	37	0.5	37	0.5	37	0.5	37	
		to output A	-40°C to 125°C	0.5	40	0.5	40	0.5	40	0.5	40	
<sup>L</sup> dis	Disable time	From input OE	–40°C to 85°C	0.5	33	0.5	30	0.5	27	0.5	57	ns
		to output B	-40°C to 125°C	0.5	36	0.5	33	0.5	29	0.5	60	
		–40°C to 85°C	0.5	17	0.5	17	0.5	17	0.5	17		
		to output A	-40°C to 125°C	0.5	19	0.5	19	0.5	19	0.5	19	
Len		From input OE	–40°C to 85°C	0.5	15	0.5	13	0.5	10	0.5	9	ns
		to output B	–40°C to 125°C	0.5	16	0.5	14	0.5	11	0.5	10	

## 5.12 Switching Characteristics, $V_{CCA} = 2.5V$

See Figure 6-1 and Figure 6-2 for test circuit and loading conditions. See Figure 6-3 and Figure 6-4 for measurement waveforms.

						B-PORT	SUPPLY V	OLTAGE (	V <sub>CCB</sub> )			
P	ARAMETER	TEST CO	NDITIONS	0.7V :	± 0.05V	0.8V	± 0.04V	0.9V ±	0.045V	1.2V	± 0.1V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	81	0.5	40	0.5	22	0.5	8	
	Propagation	to output B	-40°C to 125°C	0.5	81	0.5	40	0.5	22	0.5	8	no
t <sub>pd</sub>	delay	From input B	-40°C to 85°C	0.5	61	0.5	25	0.5	14	0.5	7	ns
		to output A	-40°C to 125°C	0.5	61	0.5	25	0.5	14	0.5	7	
		From input OE	-40°C to 85°C	0.5	25	0.5	25	0.5	25	0.5	25	
	Disable time	to output A	-40°C to 125°C	0.5	28	0.5	28	0.5	28	0.5	28	no
t <sub>dis</sub>	Disable time	From input OE	-40°C to 85°C	0.5	111	0.5	85	0.5	76	0.5	81	ns
		to output B	-40°C to 125°C	0.5	113	0.5	87	0.5	78	0.5	84	
		From input OE	-40°C to 85°C	0.5	11	0.5	11	0.5	11	0.5	11	
t <sub>en</sub>	Enable time	to output A	-40°C to 125°C	0.5	12	0.5	12	0.5	12	0.5	12	no
	Enable time	From input OE	-40°C to 85°C	0.5	155	0.5	86	0.5	52	0.5	21	ns
		to output B	-40°C to 125°C	0.5	155	0.5	86	0.5	52	0.5	21	

## Switching Characteristics, $V_{CCA} = 2.5V$

						B-PORT	SUPPLY V	OLTAGE (	V <sub>CCB</sub> )			
F	PARAMETER	TEST CC	NDITIONS	1.5V	± 0.1V	1.8V ±	: 0.15V	2.5V	± 0.2V	3.3V	± 0.3V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	6	0.5	5	0.5	4	0.5	4	
	Propagation	to output B	-40°C to 125°C	0.5	6	0.5	5	0.5	5	0.5	4	ns
t <sub>pd</sub>	· uciay	From input B	-40°C to 85°C	0.5	6	0.5	5	0.5	4	0.5	4	1115
		to output A	-40°C to 125°C	0.5	6	0.5	5	0.5	5	0.5	4	
		From input OE	-40°C to 85°C	0.5	25	0.5	25	0.5	25	0.5	25	
	Disable time	to output A	-40°C to 125°C	0.5	28	0.5	28	0.5	28	0.5	28	no
t <sub>dis</sub>	Disable time	From input OE	-40°C to 85°C	0.5	31	0.5	28	0.5	25	0.5	23	ns
		to output B	-40°C to 125°C	0.5	34	0.5	31	0.5	28	0.5	25	
		From input OE	-40°C to 85°C	0.5	11	0.5	11	0.5	11	0.5	11	
	Enable time	to output A	-40°C to 125°C	0.5	12	0.5	12	0.5	12	0.5	12	
t <sub>en</sub>	Eliable tille	From input OE	-40°C to 85°C	0.5	14	0.5	11	0.5	9	0.5	7	ns
		to output B	-40°C to 125°C	0.5	14	0.5	12	0.5	9	0.5	8	



## 5.13 Switching Characteristics, $V_{CCA} = 3.3V$

See Figure 6-1 and Figure 6-2 for test circuit and loading conditions. See Figure 6-3 and Figure 6-4 for measurement waveforms.

						B-POR	T SUPPLY	VOLTAGE	(V <sub>CCB</sub> )			
P	ARAMETER	TEST CO	ONDITIONS	0.7V :	± 0.05V	0.8V	± 0.04V	0.9V ±	0.045V	1.2V	± 0.1V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	81	0.5	40	0.5	22	0.5	7	
	Propagation	to output B	–40°C to 125°C	0.5	81	0.5	40	0.5	22	0.5	7	no
t <sub>pd</sub>	delay	From input B	–40°C to 85°C	0.5	142	0.5	35	0.5	17	0.5	7	ns
		to output A	-40°C to 125°C	0.5	142	0.5	35	0.5	17	0.5	8	
		From input OE	–40°C to 85°C	0.5	22	0.5	22	0.5	22	0.5	22	
	Disable time	to output A	–40°C to 125°C	0.5	24	0.5	24	0.5	24	0.5	24	
t <sub>dis</sub>	Disable time	From input OE	–40°C to 85°C	0.5	111	0.5	84	0.5	75	0.5	80	ns
		to output B	–40°C to 125°C	0.5	113	0.5	86	0.5	78	0.5	83	
		From input OE	–40°C to 85°C	0.5	9	0.5	9	0.5	9	0.5	9	
t <sub>en</sub>	For abla times	to output A	-40°C to 125°C	0.5	10	0.5	10	0.5	10	0.5	10	
	Enable time	From input OE	–40°C to 85°C	0.5	154	0.5	86	0.5	51	0.5	20	ns
		to output B	–40°C to 125°C	0.5	154	0.5	86	0.5	51	0.5	20	

## Switching Characteristics, V<sub>CCA</sub> = 3.3V

						B-POR	T SUPPLY	VOLTAGE	(V <sub>CCB</sub> )			
ı	PARAMETER	TEST CO	ONDITIONS	1.5V	± 0.1V	1.8V ±	0.15V	2.5V	± 0.2V	3.3V	± 0.3V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		From input A	-40°C to 85°C	0.5	5	0.5	4	0.5	4	0.5	4	
	Propagation	to output B	-40°C to 125°C	0.5	5	0.5	4	0.5	4	0.5	4	ns
t <sub>pd</sub>	delay	From input B	-40°C to 85°C	0.5	5	0.5	5	0.5	4	0.5	4	1115
		to output A	-40°C to 125°C	0.5	6	0.5	5	0.5	4	0.5	4	
		From input OE	-40°C to 85°C	0.5	22	0.5	22	0.5	22	0.5	22	
	Disable time	to output A	–40°C to 125°C	0.5	24	0.5	24	0.5	24	0.5	24	ns
t <sub>dis</sub>	Disable time	From input OE	–40°C to 85°C	0.5	30	0.5	27	0.5	25	0.5	23	i iis
		to output B	–40°C to 125°C	0.5	33	0.5	30	0.5	27	0.5	25	
		From input OE	–40°C to 85°C	0.5	9	0.5	9	0.5	9	0.5	9	
	Englishing	to output A	–40°C to 125°C	0.5	10	0.5	10	0.5	10	0.5	10	
t <sub>en</sub>	Enable time	From input OE	-40°C to 85°C	0.5	13	0.5	10	0.5	8	0.5	7	ns
		to output B	-40°C to 125°C	0.5	14	0.5	11	0.5	8	0.5	7	1



# 5.14 Operating Characteristics: $T_A = 25$ °C

	PARAMETER	TES	MIN TYP MAX	UNIT					
			V <sub>CCA</sub> = V <sub>CCB</sub> = 0.7V	1.2					
			$V_{CCA} = V_{CCB} = 0.8V$	1.8					
			$V_{CCA} = V_{CCB} = 0.9V$	1.8					
^	Power dissipation	C <sub>L</sub> = 0, R <sub>L</sub> = Open	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.2V	1.7					
<b>-</b> pdA	capacitance per transceiver (A to B: outputs enabled)	$f = 1MHz$ , $t_r = t_f = 1 \text{ ns}$	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.5V	1.7	рг				
	,		V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8V	1.7					
			V <sub>CCA</sub> = V <sub>CCB</sub> = 2.5V	2					
			$V_{CCA} = V_{CCB} = 3.3V$	2.5					
			V <sub>CCA</sub> = V <sub>CCB</sub> = 0.7V	1.1					
			$V_{CCA} = V_{CCB} = 0.8V$	1.8					
			$V_{CCA} = V_{CCB} = 0.9V$	1.8	pF pF				
_	Power dissipation	$C_L = 0$ , $R_L = Open$	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.2V	1.7					
	capacitance per transceiver (A to B: outputs disabled)	$f = 1MHz$ , $t_r = t_f = 1 \text{ ns}$	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.5V	1.7					
	,		V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8V	1.7					
			$V_{CCA} = V_{CCB} = 2.5V$	2					
			V <sub>CCA</sub> = V <sub>CCB</sub> = 3.3V	2.1					
			V <sub>CCA</sub> = V <sub>CCB</sub> = 0.7V	9.3					
			$V_{CCA} = V_{CCB} = 0.8V$	11.8					
			$V_{CCA} = V_{CCB} = 0.9V$	11.8					
,	Power dissipation	$C_L = 0$ , $R_L = Open$	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.2V	12					
SpdA	capacitance per transceiver (B to A: outputs enabled)	$f = 1MHz$ , $t_r = t_f = 1 \text{ ns}$	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.5V	12.2	p⊢				
	,		V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8V	13					
			V <sub>CCA</sub> = V <sub>CCB</sub> = 2.5V	16.4					
			V <sub>CCA</sub> = V <sub>CCB</sub> = 3.3V	18.1	7				
			$V_{CCA} = V_{CCB} = 0.7V$	2.6					
			V <sub>CCA</sub> = V <sub>CCB</sub> = 0.8V	1.2					
			V <sub>CCA</sub> = V <sub>CCB</sub> = 0.9V	1.1					
	Power dissipation	C <sub>L</sub> = 0, R <sub>L</sub> = Open	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.2V	1.2					
pdA	capacitance per transceiver (B to A: outputs disabled)	$f = 1MHz$ , $t_r = t_f = 1 \text{ ns}$	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.5V	1.2	pF				
	(D to A. outputs disabled)		V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8V	1.3					
			V <sub>CCA</sub> = V <sub>CCB</sub> = 2.5V	1.6					
			V <sub>CCA</sub> = V <sub>CCB</sub> = 3.3V	3.9					



## 5.14 Operating Characteristics: T<sub>A</sub> = 25°C (continued)

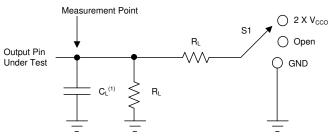
	PARAMETER	TES	ST CONDITIONS	MIN TYP	MAX	UNIT	
			$V_{CCA} = V_{CCB} = 0.7V$	9.3			
			$V_{CCA} = V_{CCB} = 0.8V$	11.7		pF pF	
			$V_{CCA} = V_{CCB} = 0.9V$	11.8			
	Power dissipation	C <sub>L</sub> = 0, R <sub>L</sub> = Open	$V_{CCA} = V_{CCB} = 1.2V$	11.9			
C <sub>pdB</sub>	capacitance per transceiver (A to B: outputs enabled)	$f = 1MHz$ , $t_r = t_f = 1 ns$	$V_{CCA} = V_{CCB} = 1.5V$	12.2		pF	
	,		$V_{CCA} = V_{CCB} = 1.8V$	12.9			
			$V_{CCA} = V_{CCB} = 2.5V$	16.3			
			$V_{CCA} = V_{CCB} = 3.3V$	18			
			$V_{CCA} = V_{CCB} = 0.7V$	2.6			
			$V_{CCA} = V_{CCB} = 0.8V$	11.7			
			$V_{CCA} = V_{CCB} = 0.9V$	11.8		pF	
	Power dissipation	C <sub>L</sub> = 0, R <sub>L</sub> = Open	$V_{CCA} = V_{CCB} = 1.2V$	11.9			
C <sub>pdB</sub>	capacitance per transceiver (A to B: outputs disabled)	$f = 1MHz$ , $t_r = t_f = 1 \text{ ns}$	$V_{CCA} = V_{CCB} = 1.5V$	12.2			
	,		$V_{CCA} = V_{CCB} = 1.8V$	12.9			
			$V_{CCA} = V_{CCB} = 2.5V$	16.3			
			$V_{CCA} = V_{CCB} = 3.3V$	3.9			
			$V_{CCA} = V_{CCB} = 0.7V$	1.2			
			$V_{CCA} = V_{CCB} = 0.8V$	1.8			
			$V_{CCA} = V_{CCB} = 0.9V$	1.8			
	Power dissipation	C <sub>L</sub> = 0, R <sub>L</sub> = Open	$V_{CCA} = V_{CCB} = 1.2V$	1.7			
C <sub>pdB</sub>	capacitance per transceiver (B to A: outputs enabled)	$f = 1MHz$ , $t_r = t_f = 1 ns$	$V_{CCA} = V_{CCB} = 1.5V$	1.7		pF	
	,		$V_{CCA} = V_{CCB} = 1.8V$	1.7			
			$V_{CCA} = V_{CCB} = 2.5V$	2			
			$V_{CCA} = V_{CCB} = 3.3V$	2.5			
			$V_{CCA} = V_{CCB} = 0.7V$	1.1			
			$V_{CCA} = V_{CCB} = 0.8V$	1.8			
			$V_{CCA} = V_{CCB} = 0.9V$	1.8			
_	Power dissipation	$C_L = 0$ , $R_L = Open$	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.2V	1.7			
C <sub>pdB</sub>	capacitance per transceiver (B to A: outputs disabled)	$f = 1MHz$ , $t_r = t_f = 1 \text{ ns}$	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.5V	1.7		pF	
	, ,	$V_{CCA} = V_{CCB} = 1.8V$	$V_{CCA} = V_{CCB} = 1.8V$	1.7			
			V <sub>CCA</sub> = V <sub>CCB</sub> = 2.5V	2			
			$V_{CCA} = V_{CCB} = 3.3V$	2.1			

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#### **6 Parameter Measurement Information**

Unless otherwise noted, all input pulses are supplied by generators having the following characteristics:

- f =1MHz
- $Z_0 = 50 \Omega$
- dv / dt ≤ 1 ns/V



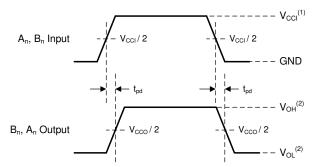
A. C<sub>L</sub> includes probe and jig capacitance.

Figure 6-1. Load Circuit

Parameter	V <sub>cco</sub>	RL	CL	S1	$V_{TP}$
t <sub>pd</sub>	1.1 V - 3.6 V	2 kΩ	15 pF	Open	N/A
·pα	0.65 V - 0.95 V	20 kΩ	15 pF	Open	N/A
	3 V - 3.6 V	2 kΩ	15 pF	2 X V <sub>CCO</sub>	0.3 V
. (1) . (1)	1.65 V - 2.7 V	2 kΩ	15 pF	2 X V <sub>CCO</sub>	0.15 V
t <sub>en</sub> <sup>(1)</sup> , t <sub>dis</sub> <sup>(1)</sup>	1.1 V - 1.6 V	2 kΩ	15 pF	2 X V <sub>CCO</sub>	0.1 V
	0.65 V - 0.95 V	20 kΩ	15 pF	2 X V <sub>CCO</sub>	0.1 V
	3 V - 3.6 V	2 kΩ	15 pF	GND	0.3 V
t <sub>en</sub> (2), t <sub>dis</sub> (2)	1.65V - 2.7 V	2 kΩ	15 pF	GND	0.15 V
-on , suis	1.1 V - 1.6 V	2 kΩ	15 pF	GND	0.1 V
	0.65 V - 0.95 V	20 kΩ	15 pF	GND	0.1 V

- A. Output waveform on the conditions that input is driven to a valid Logic Low.
- B. Output waveform on the condition that input is driven to a valid Logic High.

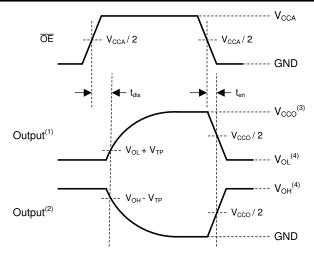
Figure 6-2. Load Circuit Conditions



- A. V<sub>CCI</sub> is the supply pin associated with the input port.
- B.  $V_{OH}$  and  $V_{OL}$  are typical output voltage levels with specified  $R_L$ ,  $C_L$ , and  $S_1$ .

Figure 6-3. Propagation Delay





- A. Output waveform on the condition that input is driven to a valid Logic Low.
- B. Output waveform on the condition that input is driven to a valid Logic High.
- C.  $V_{\text{CCO}}$  is the supply pin associated with the output port.
- D.  $\;\;$  V<sub>OH</sub> and V<sub>OL</sub> are typical output voltage levels with specified R<sub>L</sub>, C<sub>L</sub>, and S<sub>1</sub>.

Figure 6-4. Enable Time And Disable Time

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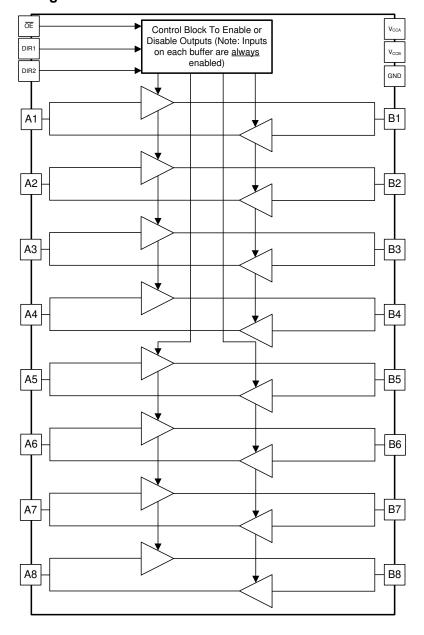


### 7 Detailed Description

#### 7.1 Overview

The SN74AXC8T245 device is an 8-bit, dual-supply non-inverting transceiver with bidirectional voltage level translation. The I/O pins labeled with A and the control pins (DIR1, DIR2, and  $\overline{\text{OE}}$ ) are supported by  $V_{\text{CCA}}$ , and the I/O pins labeled with B are supported by  $V_{\text{CCB}}$ . The A port and the B port are able to accept I/O voltages ranging from 0.65V to 3.6V.

### 7.2 Functional Block Diagram



#### 7.3 Feature Description

#### 7.3.1 Up-Translation and Down-Translation From 0.65V to 3.6V

Both supply pins are configured from 0.65V to 3.6V, which makes the device suitable for translating between any of the low voltage nodes (0.7V, 0.8V, 0.9V, 1.2V, 1.8V, 2.5V, and 3.3V).

#### 7.3.2 Multiple Direction Control Pins

Two control pins are used to configure the 8 data I/Os. I/O channels 1 through 4 are grouped together and I/O channels 5 through 8 are banked together. The benefit of this is to permit simultaneous up-translation and down-translation within one device. This eliminates the need for multiple devices, where each device can only provide up-translation or down-translation sequentially. Simultaneous up and down translation is supported when both  $V_{\rm CCA}$  and  $V_{\rm CCB}$  are at least 1.40V.

#### 7.3.3 I<sub>off</sub> Supports Partial-Power-Down Mode Operation

This feature is to limit the leakage current of an I/O pin being driven to a voltage as large as 3.6V while having its corresponding power supply rail powered down. This is represented by the I<sub>off</sub> parameter in the *Electrical Characteristics* table.

#### 7.3.4 I/Os with Integrated Static Pull-Down Resistors

To help avoid floating inputs on the I/Os, this device has  $288k\Omega$  typical integrated weak pull-downs on all data I/Os. This feature allows all inputs to be left floating without the concern for unstable outputs or increased current consumption. This also helps to reduce external component count for applications where not all channels are used or need to be fixed low. If an external pull-up is required, it should be no larger than  $30k\Omega$  to avoid contention with the  $288k\Omega$  internal pull-down.

#### 7.4 Device Functional Modes

All control inputs are referenced to  $V_{CCA}$  and must be driven to a valid Logic High or Logic Low (that is, not floating) to assure proper device operation and to prevent excessive power consumption. Table 7-1 summarizes the possible modes of device operation based on the configuration of the control inputs.

	CONTROL INPUTS	)	Signal Direction				
ŌĒ	DIR1	DIR2	Bits 1:4	Bits 5:8			
Н	X	X	Disabled (Hi-Z)				
L	L	L	B to A				
L	L	Н	B to A	A to B			
L	Н	L	A to B				
L	Н	Н	A to B B to A				

**Table 7-1. Function Table** 

(1) Input circuits of the data I/Os are always active and must be driven to a valid logic level.



#### 8 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

#### 8.1 Application Information

The SN74AXC8T245 device can be used in level-translation applications for interfacing devices or systems operating at different voltage nodes. Figure 9-1 depicts an application in which the SN74AXC8T245 device is up-translating a 0.7V input to a 3.3V output to interface between a system controller and a peripheral device.

#### 8.2 Typical Application

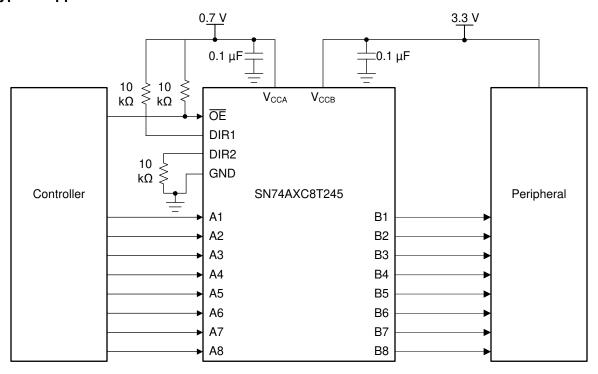


Figure 8-1. Typical Application Schematic



#### 8.2.1 Design Requirements

For this design example, use the parameters listed in Table 8-1.

**Table 8-1. Design Parameters** 

DESIGN PARAMETERS	EXAMPLE VALUE
Input voltage range	0.65V to 3.6V
Output voltage range	0.65V to 3.6V

#### 8.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- · Input voltage range
  - Use the supply voltage of the device that is driving the SN74AXC8T245 device to determine the input voltage range. For a valid logic high the value must exceed the  $V_{IH}$  of the input port. For a valid logic low the value must be less than the  $V_{IL}$  of the input port.
- · Output voltage range
  - Use the supply voltage of the device that the SN74AXC8T245 device is driving to determine the output voltage range.

#### 8.2.3 Application Curve

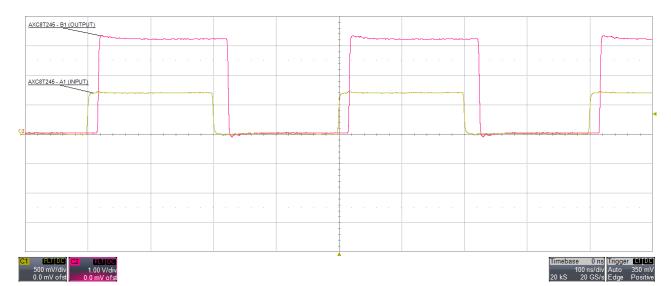


Figure 8-2. Translation Up (0.7V to 3.3V) at 2.5MHz

#### 8.3 Power Supply Recommendations

Always apply a ground reference to the GND pins first. There are no additional requirements for power supply sequencing.

This device was designed with various power supply sequencing methods in mind to help prevent unintended triggering of downstream devices. For more information regarding the power up glitch performance of the AXC family of level translators, see the *Power Sequencing for AXC Family of Devices* application report.

#### 8.4 Layout

#### 8.4.1 Layout Guidelines

For device reliability, follow common printed-circuit board layout guidelines.

- · Use bypass capacitors on power supplies.
- Use short trace lengths to avoid excessive loading.
- Place pads on the signal paths for loading capacitors or pullup resistors to help adjust rise and fall times of signals depending on the system requirements.

#### 8.4.2 Layout Example

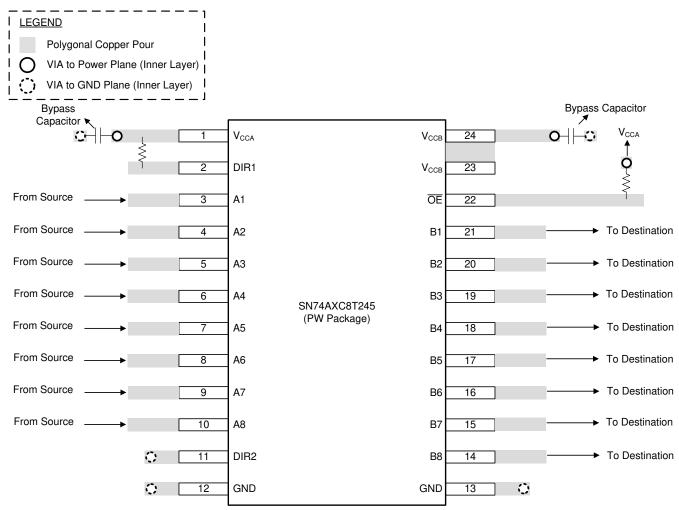


Figure 8-3. SN74AXC8T245 Device Layout Example

#### 9 Device and Documentation Support

#### 9.1 Documentation Support

#### 9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, SN74AXC8245-Q1 Evaluation Module user's guide
- Texas Instruments, Implications of Slow or Floating CMOS Inputs application report
- Texas Instruments, Power Sequencing for AXC Family of Devices application report

#### 9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on Notifications to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 9.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 9.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

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#### 9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

#### 10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (August 2018) to Revision C (January 2024)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document	2
Added the I <sub>off</sub> Supports Partial-Power-Down Mode Operation section	20
Changes from Revision A (July 2018) to Revision B (August 2018)	Page
Changed data sheet status from Mixed Production to Production Data	1
Removed package preview note from RJW package	

### 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 17-Jun-2025

#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
SN74AXC8T245PWR	Active	Production	TSSOP (PW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AX8T245
SN74AXC8T245PWR.B	Active	Production	TSSOP (PW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AX8T245
SN74AXC8T245PWRG4	Active	Production	TSSOP (PW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AX8T245
SN74AXC8T245PWRG4.B	Active	Production	TSSOP (PW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AX8T245
SN74AXC8T245RHLR	Active	Production	VQFN (RHL)   24	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AX8T245
SN74AXC8T245RHLR.B	Active	Production	VQFN (RHL)   24	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AX8T245
SN74AXC8T245RHLRG4	Active	Production	VQFN (RHL)   24	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AX8T245
SN74AXC8T245RHLRG4.B	Active	Production	VQFN (RHL)   24	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AX8T245
SN74AXC8T245RJWR	Active	Production	UQFN (RJW)   24	3000   LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AX8T245
SN74AXC8T245RJWR.B	Active	Production	UQFN (RJW)   24	3000   LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AX8T245

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## PACKAGE OPTION ADDENDUM

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and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN74AXC8T245:

Automotive: SN74AXC8T245-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

## **PACKAGE MATERIALS INFORMATION**

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#### TAPE AND REEL INFORMATION





	•
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AXC8T245RHLR	VQFN	RHL	24	3000	330.0	12.4	3.8	5.8	1.2	8.0	12.0	Q1
SN74AXC8T245RHLRG4	VQFN	RHL	24	3000	330.0	12.4	3.8	5.8	1.2	8.0	12.0	Q1
SN74AXC8T245RJWR	UQFN	RJW	24	3000	177.8	12.4	2.21	4.22	0.81	4.0	12.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AXC8T245RHLR	VQFN	RHL	24	3000	367.0	367.0	35.0
SN74AXC8T245RHLRG4	VQFN	RHL	24	3000	367.0	367.0	35.0
SN74AXC8T245RJWR	UQFN	RJW	24	3000	183.0	183.0	20.0



SMALL OUTLINE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE

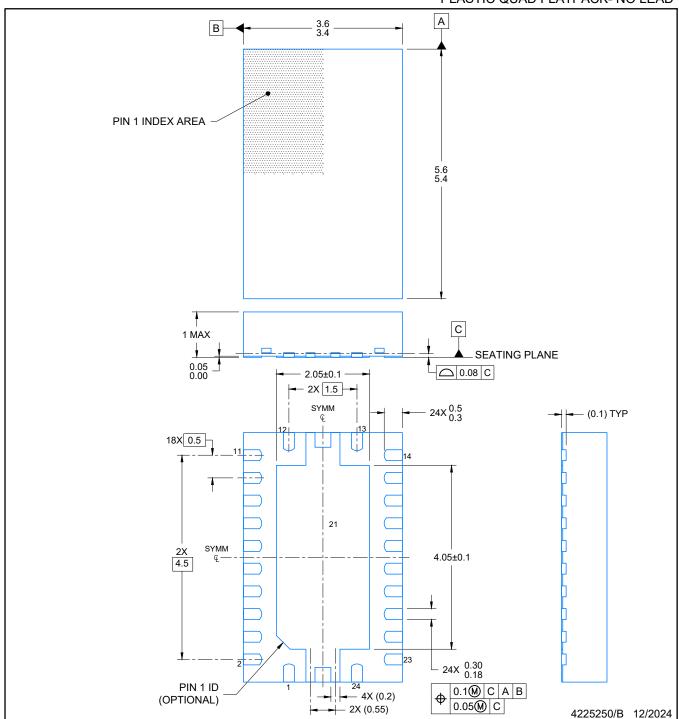


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PLASTIC QUAD FLATPACK- NO LEAD

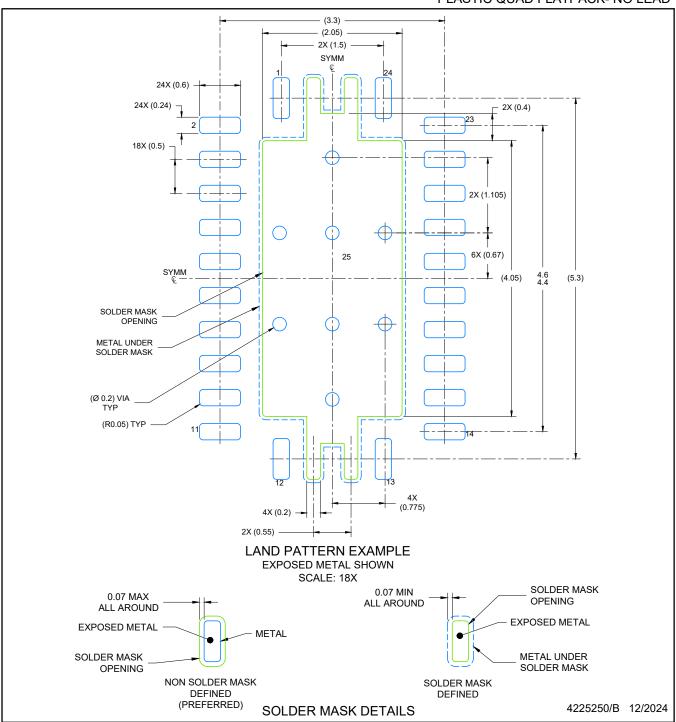


#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



PLASTIC QUAD FLATPACK- NO LEAD

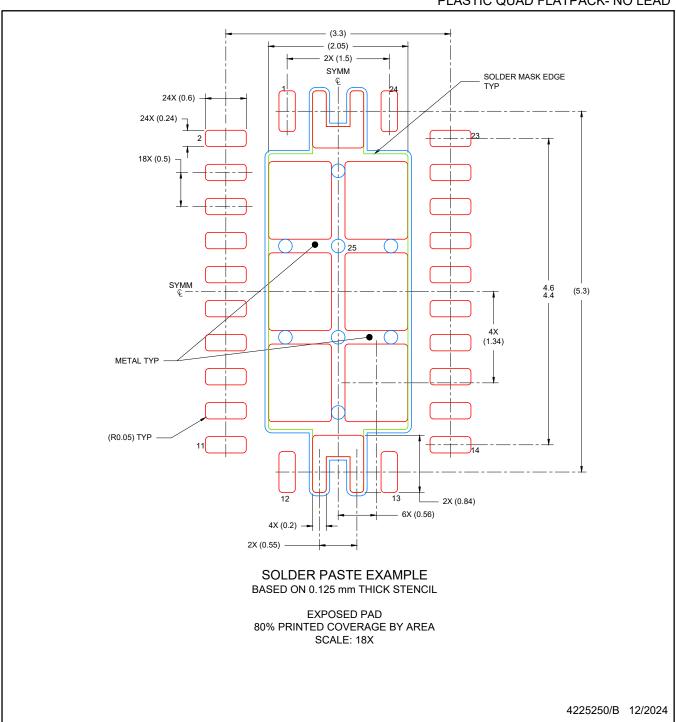


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK- NO LEAD



NOTES: (continued)

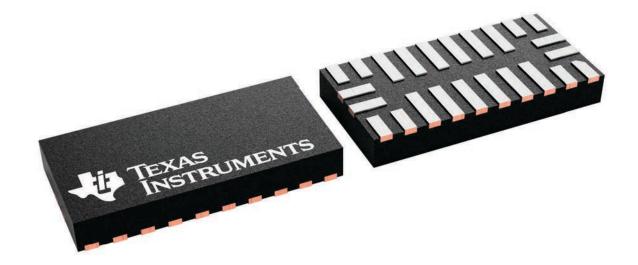
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



2 x 4, 0.4 mm pitch

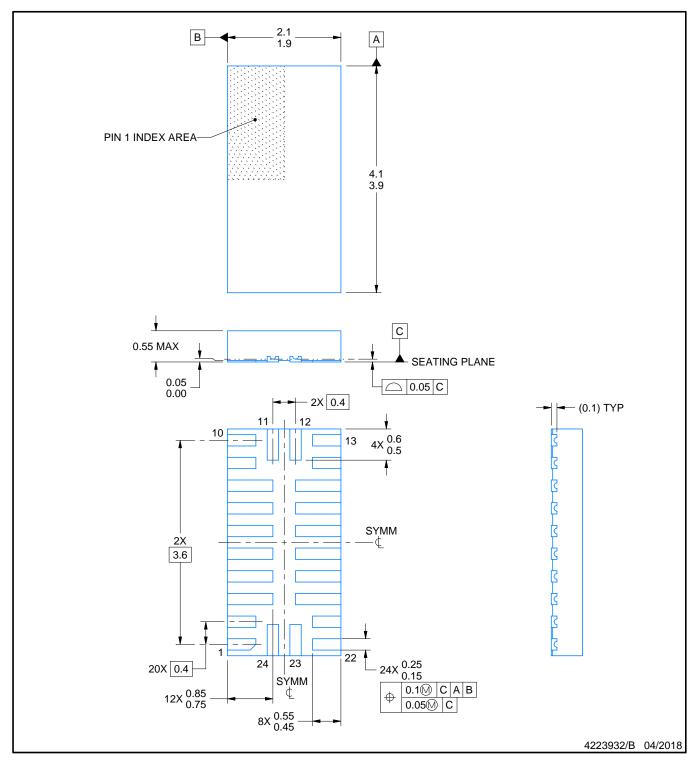
PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD



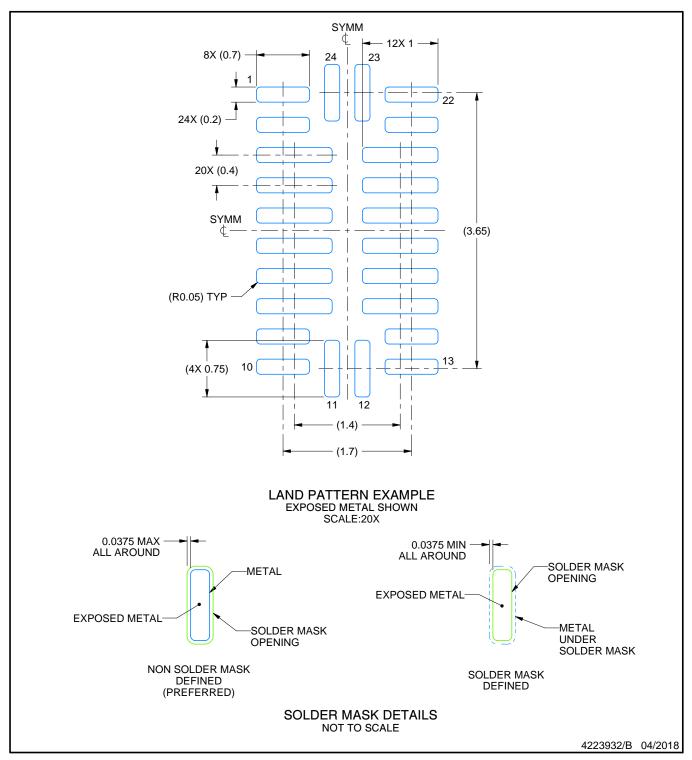
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.



PLASTIC QUAD FLATPACK - NO LEAD

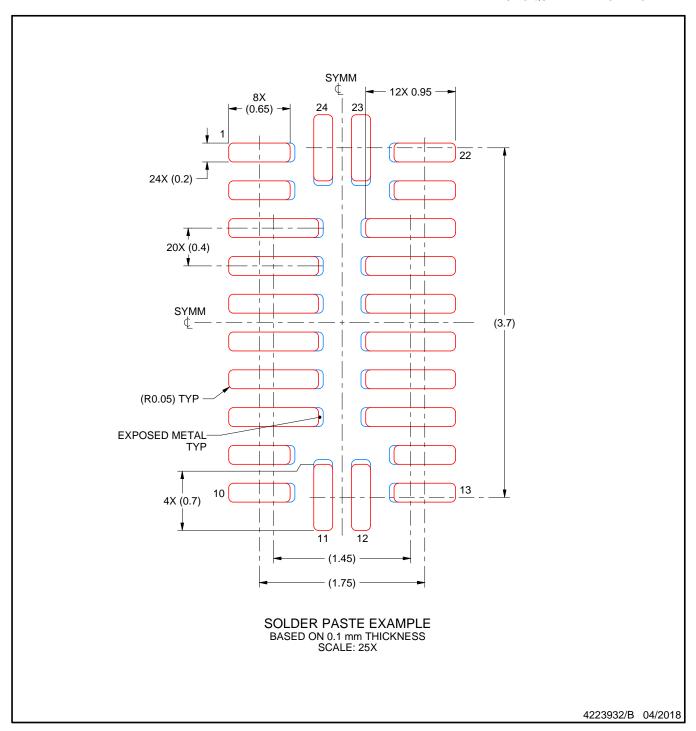


NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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